

Interference Search History printout MT

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(memory and gate near insulator and storage near node and tunnel adj junction adj barrier and data adj electrode).CLM.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/11/21 12:01